NEC

1.6 GHz DIFFERENTIAL WIDEBAND SILICON RFIC AMPLIFIER

UPC2726T

FEATURES

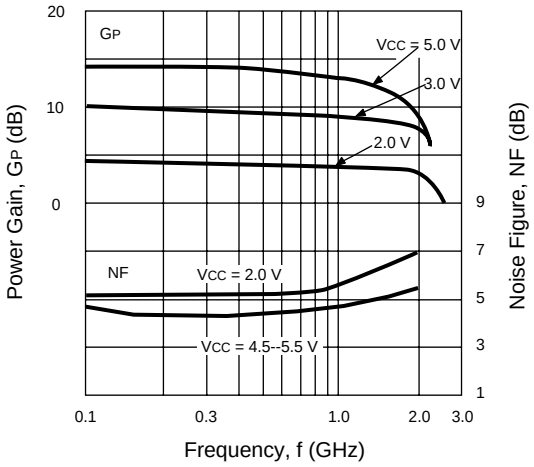
- **HIGH GAIN:** 15 dB Typical at 400 MHz
- **WIDEBAND FREQUENCY RESPONSE:** 1.6 GHz TYP
- **SINGLE POSITIVE DC SUPPLY**
- **SUPER SMALL PACKAGE**
- **TAPE AND REEL PACKAGING OPTION AVAILABLE**

DESCRIPTION

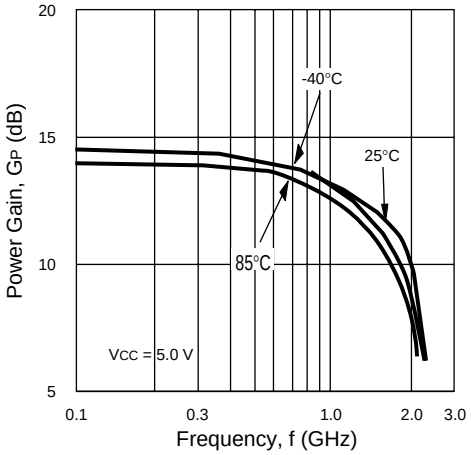
The UPC2726T is a Silicon RF Integrated Citrcuit which is manufactured using the NESAT III process. The NESAT III process produces transistors with f_T approaching 20 GHz. This amplifier was designed as a buffer amplifier for circuits requiring differential inputs and outputs for increased common-mode rejection.

NEC's stringent quality assurance and test procedures ensure the highest reliability and performance.

NOISE FIGURE AND GAIN vs. FREQUENCY AND VOLTAGE



GAIN vs. FREQUENCY AND TEMPERATURE



ELECTRICAL CHARACTERISTICS (T_A = 25°C, Z_L = Z_S = 50 Ω, f = 400 MHz)

PART NUMBER PACKAGE OUTLINE			UPC2726T					
			Vcc = 5 V			Vcc = 2 V		
SYMBOLS	PARAMETERS AND CONDITIONS	UNITS	MIN	TYP	MAX	MIN	TYP	MAX
I_{CC}	Circuit Current, (No Signal)	mA	8	11.5	15		2.5	
G_S	Small Signal Gain	dB	11	15	17		4.5	
NF	Noise Figure	dB		4.5	6		5.1	
fu	Upper limit Operating Frequency[1]	GHz	1.0	1.6			2.4	
P_{SAT}	Saturated Output Power	dBm	-5	-2			-14	
RL_{IN}	Input Return Loss	dB		2			1	
RL_{OUT}	Output Return Loss	dB		4			4	
ISOL	Isolation	dB		60			58	
OIP_3	Output 3rd Order Intercept Point[2]	dBm		-2.5			-10	

Notes:
1. The Gain at fu is 3 dB down from the gain at 400 MHz.
2. f_1 = 400 MHz, f_2 = 402 MHz, single side band.

ABSOLUTE MAXIMUM RATINGS[1] (T_A = 25°C)

SYMBOLS	PARAMETERS	UNITS	RATINGS
V_{CC}	Supply Voltage	V	6.0
P_{IN}	Input Power	dBm	0
P_T	Total Power Dissipation[2]	mW	280
T_{OP}	Operating Temperature	°C	-40 to +85
T_{STG}	Storage Temperature	°C	-55 to +150

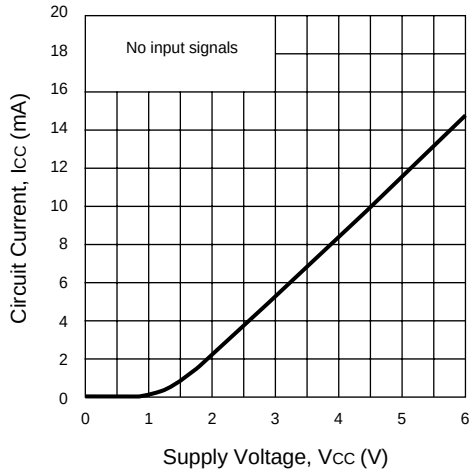
Notes:
1. Operation in excess of any one of these parameters may result in permanent damage.
2. Mounted on a 50 x 50 x 1.6 mm epoxy glass PWB (T_A = +85°C).

RECOMMENDED OPERATING CONDITIONS

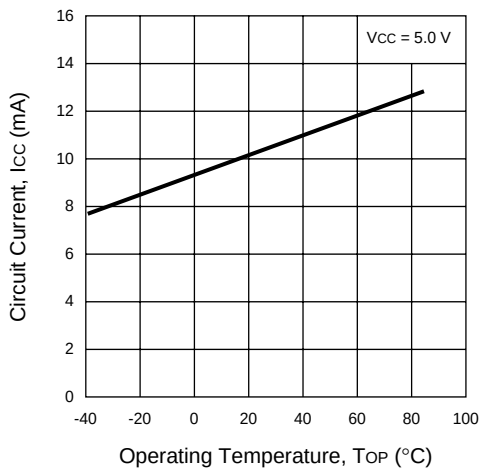
SYMBOLS	PARAMETERS	UNITS	MIN	TYP	MAX
V_{CC}	Supply Voltage	V	4.5	5.0	5.5
T_{OP}	Operating Temperature	°C	-40	25	85

TYPICAL PERFORMANCE CURVES (T_A = 25°C)

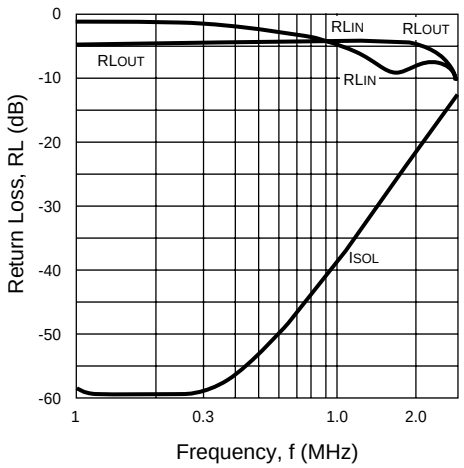
CIRCUIT CURRENT vs. VOLTAGE



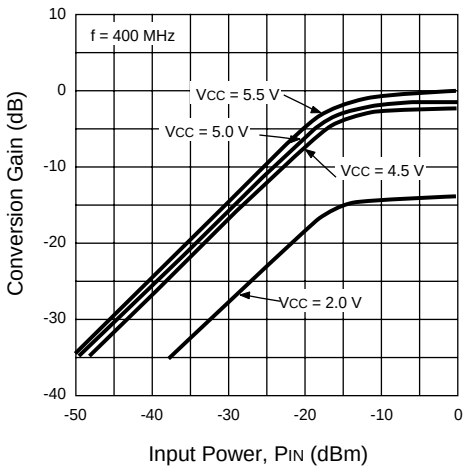
CIRCUIT CURRENT vs. OPERATING TEMPERATURE



RETURN LOSS vs. FREQUENCY

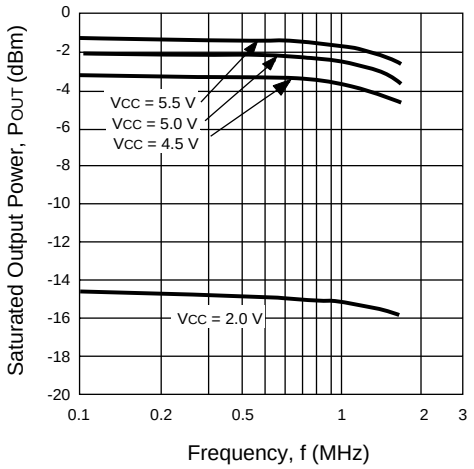


OUTPUT POWER vs. INPUT POWER and VOLTAGE

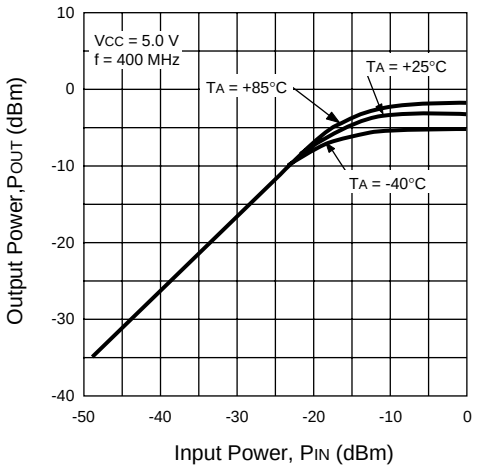


TYPICAL PERFORMANCE CURVES (T_A = 25°C)

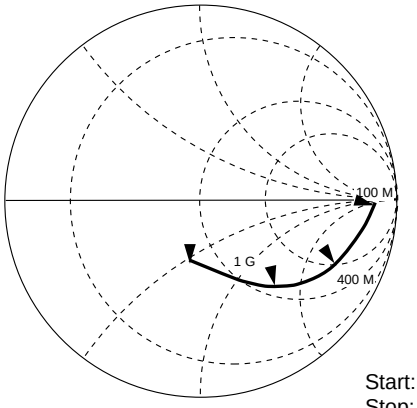
SATURATED OUTPUT POWER vs. FREQUENCY and VOLTAGE



OUTPUT POWER vs. INPUT POWER and TEMPERATURE

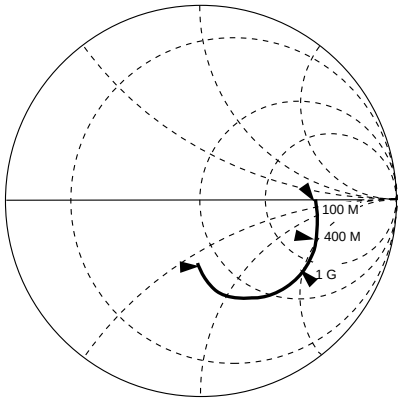


S PARAMETERS



S11

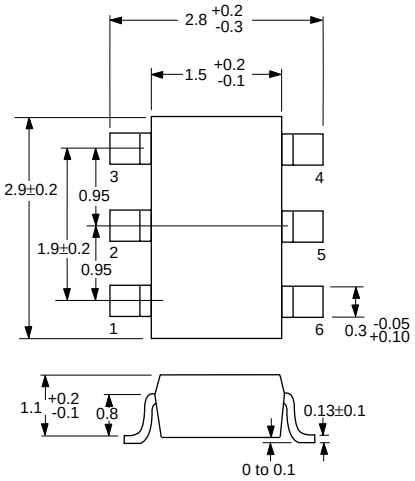
Start: 100 MHz
Stop: 2 Ghz
Conditions: T_A = 25°C, V_{CC} = 5 V



S22

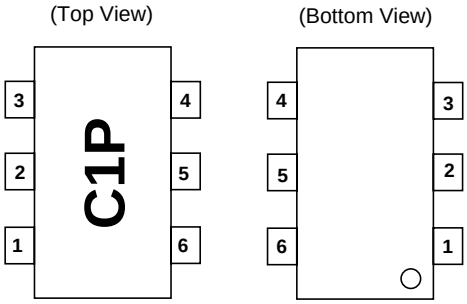
OUTLINE DIMENSIONS (Units in mm)

PACKAGE OUTLINE T06



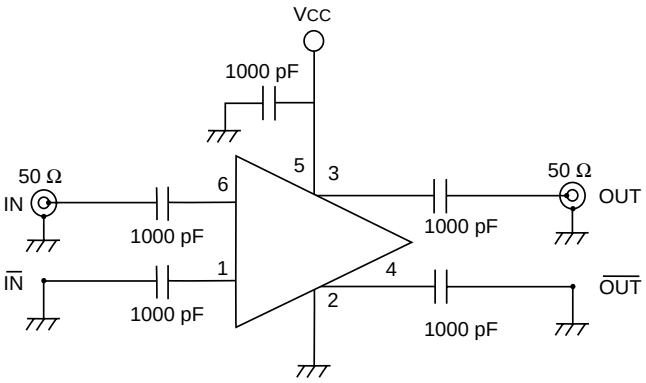
Note:
All dimensions are typical unless otherwise specified.

LEAD CONNECTIONS

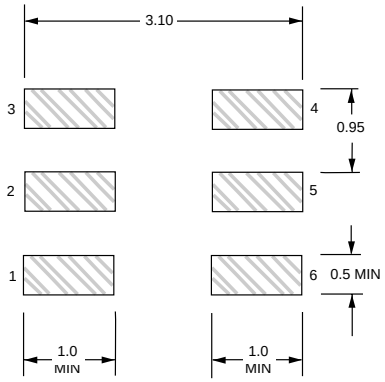


1. $\overline{\text{INPUT}}$
2. GND
3. OUTPUT
4. $\overline{\text{OUTPUT}}$
5. V_{CC}
6. INPUT

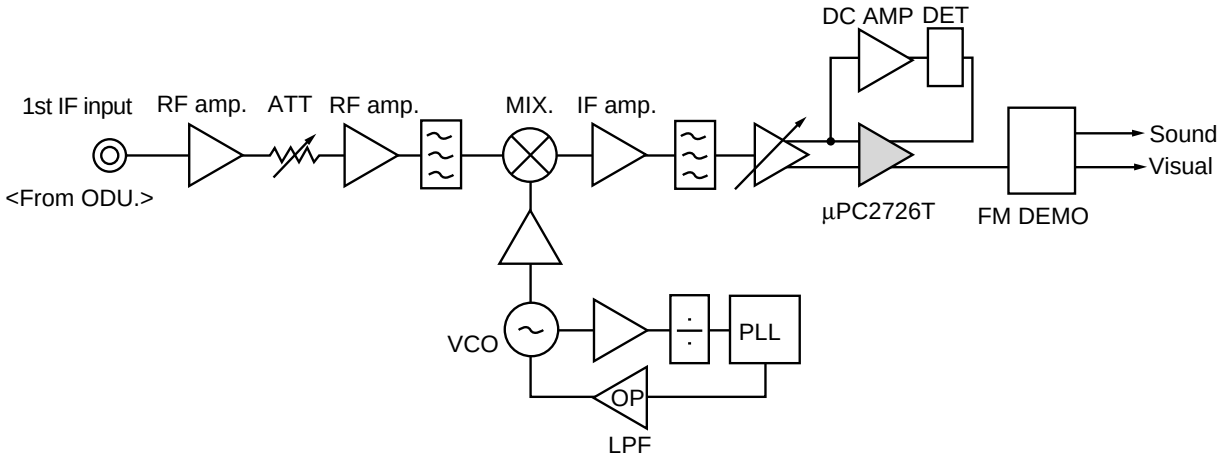
TEST CIRCUIT



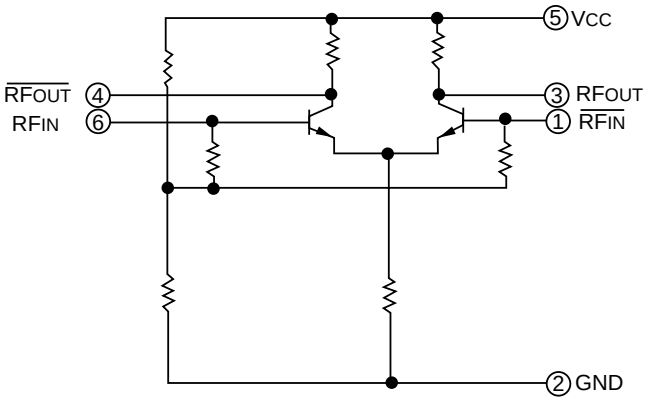
RECOMMENDED P.C.B. LAYOUT (Units in mm)



EXAMPLE OF SYSTEM APPLICATION



EQUIVALENT CIRCUIT



ORDERING INFORMATION

PART NUMBER	QTY
UPC2726T-E3	3K/Reel

Note:
Embossed Tape, 8 mm wide,

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

NEC:
UPC1663GV